Introduction to the Design of Full-Custom Front-End & Data Transmission ASICs*

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The Big (but Brief) Picture

- → Briefly **front-end** FE
- → Briefly **read-out** RO
- Briefly serializer SER
- → Briefly phase-lock loop PLL

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- → A **qualitative** introduction
- Natural frequency concept ω_n
- Real-world examples:
 - Binary read-out
 - Time-over threshold
- Adjusting/optimizing loop behavior
 - Damping ratio

Reminder on Detectors

- Photodetectors vs photon counters
- → Position-sensitive detectors
 - Resistive charge division
 - Discrete array of elements
- Time-resolved detection

Detector Front-End ASICs

- → Pre-Amp: basic idea V_{out} / V_{IN}
- → Transconductance of a transistor g_m
- Evolving a single-stage amplifier into a real-world application

Processing Technology

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 - Lithography
 - → Formation of an **nMOS** transistor
- VLSI design flow
 - Parasitic extraction
- → Real-world ASIC examples

Radiation Tolerance Issues

- Definitions:
 - Single event upset, analog single event transient, latch-up
- Simulating radiation effects on analog circuits

* Application Specific Integrated Circuit

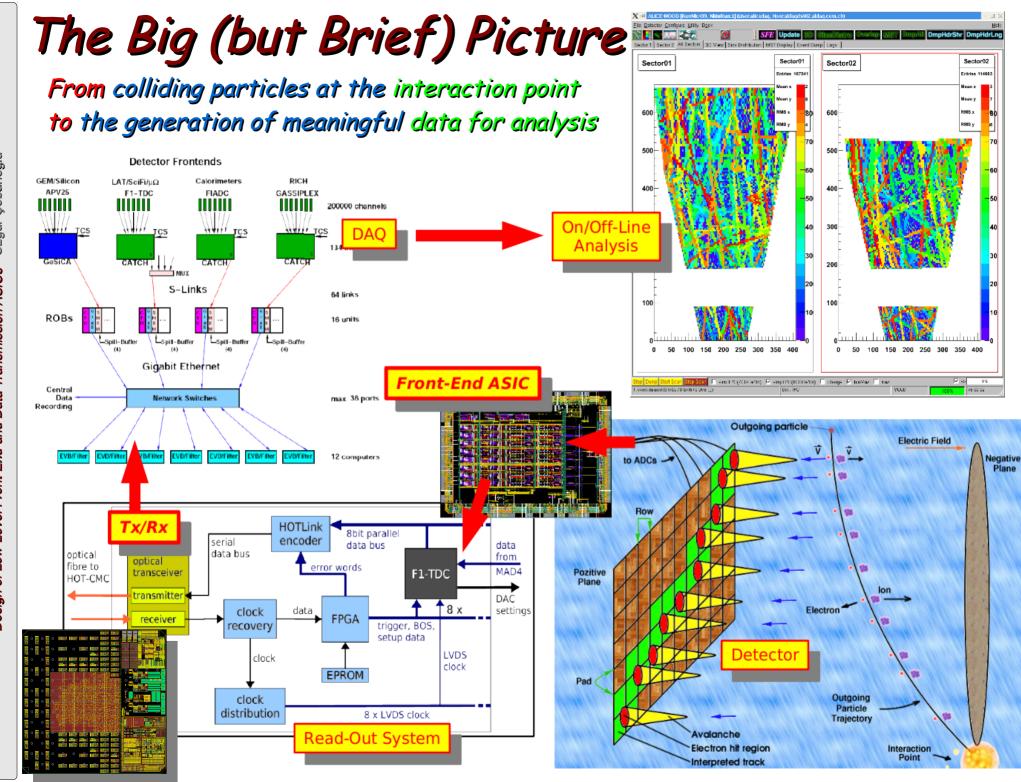
Motivation for the TOC

Composition within the ISOTDAQ curriculum

- One of the official goals of the school is to "expose the participants to a maximum variety of topics"
- What comes just after the "detector" is the first link of the DAQ chain
- Therefore this lecture will try to deliver:
 - → an intuitive approach to what is listed in the TOC
 - → without providing "dry and ugly" math phrases
- This lecture will have no specific hands-on laboratory session in the current program of the school
 - → However it will **always** be there at the lowest level of all the laboratory sessions you will attend
- The pages will contain enough amount of text necessary for you NOT to need a lecturer in order to understand the slides at home (naively assuming that you will refer to this lecture in near future)
 - → Therefore please be aware of the above fact, in case you start feeling that the pages are a little bit overloaded

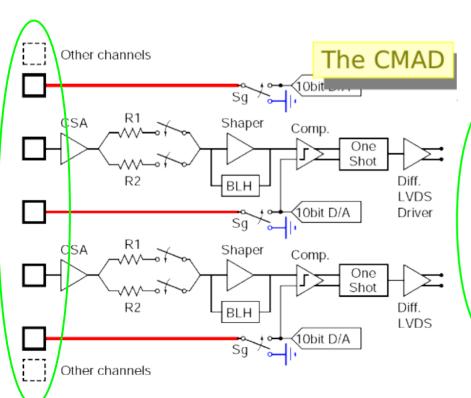
An Ordinary Heavy Ion Collusion Heavy ions at the center of ALICE detector; a short movie of 5 ns

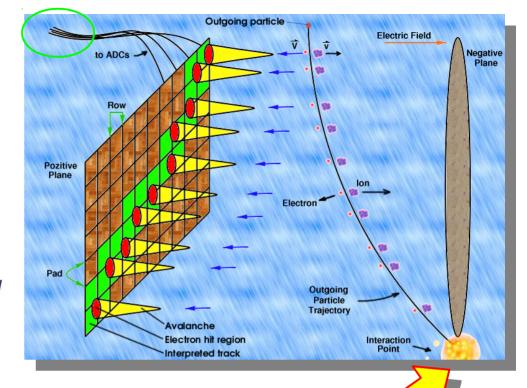


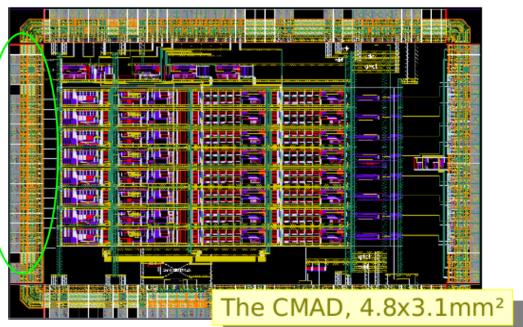


Briefly Front-End First interpretation of detector data

- Integrate the charge as a pulse
- Shape this pulse
- 1) Compare pulse height to a threshold
 - Higher ? Yes: No
- 2) Digitize the pulse for further processing
 - → Digital filters, corrections, etc.
- Send the result to read-out

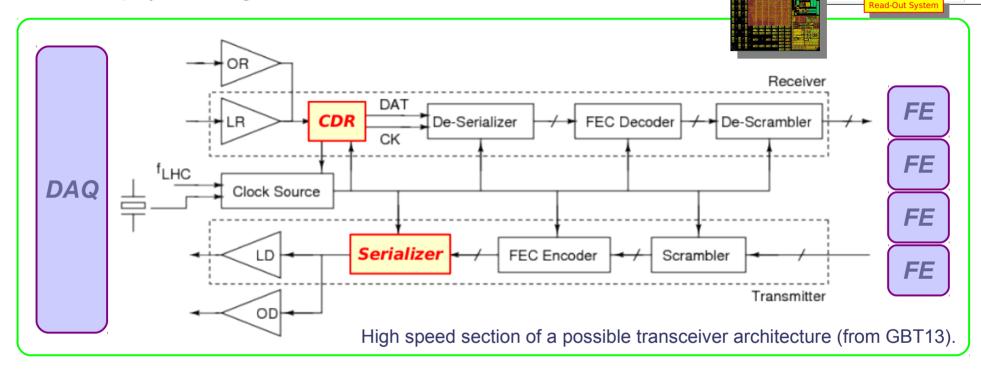






Briefly Read-Out How to get data from FE and deliver to DAQ

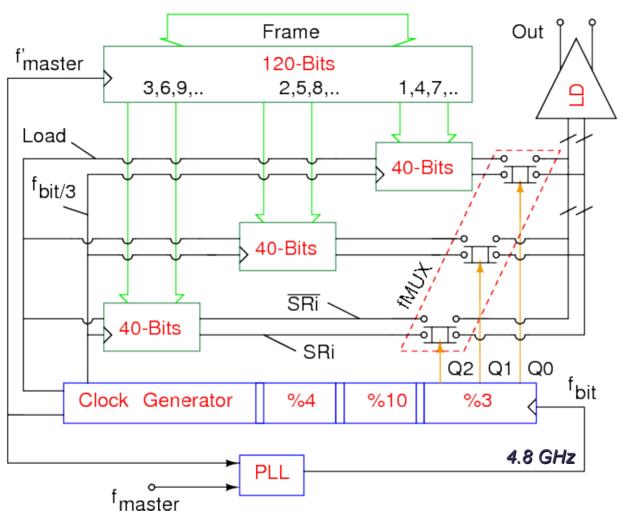
- Add *header/trailer* to the data created by the detector FEs
- Combine payload fragments into frames to be transmitted to DAQ



- Receiver
 - → Receive laser light representing serial data from fiber
 - Check FEC code and correct errors (if possible)
 - Parallelize data
 - → **Deliver** data to the next stage e.g. FE

- Transmitter:
 - Get data from FE
 - **Calculate** FEC and **add** to frame. increasing resistance against transmission errors
 - → Serialize parallel data
 - → Drive a laser diode over fiber to DAQ

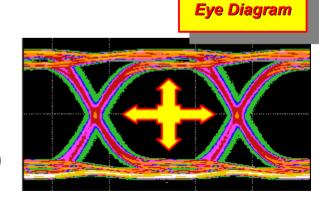
Briefly SER Parallel -> Serial



DAQ **Timing Diagram** SR0 SR2 Q0 Q1 Q2 Out

Operation:

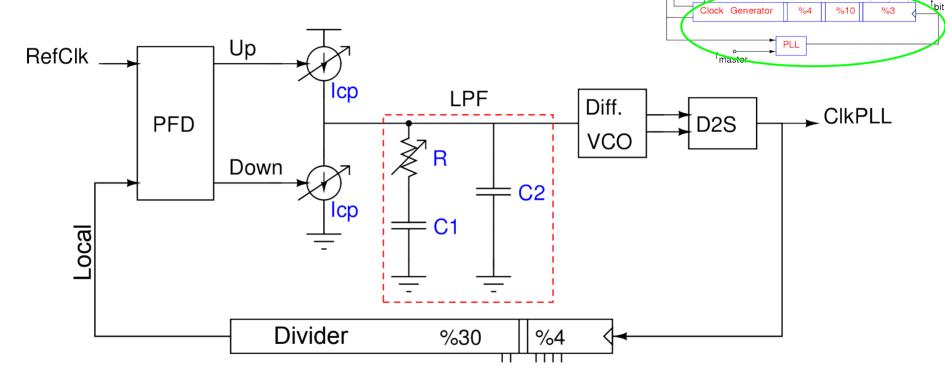
- @ rising edge of f_{MASTER}, load 120-bit-wide frame into input register (40 MHz)
- @ rising edge of Load, divide the frame into 3 40-bit-wide words (40 MHz)
- \bullet \bullet rising edge of $f_{BIT/3}$, **right shift** 30-bit-wide words **sequentially** (**1.6 GHz**)
- After every shifting, multiplex the right bit to output (4.8 GHz)



FE

Briefly PLL Phase-lock loop

- Locking a clock to a (pseudo) periodic signal
- ClkPLL is what we we generate locally and RefClk is the reference to be tracked or to be locked to



- Measure the rising instant timing difference between RefClk and ClkPLL by the phase-frequency detector (PFD)
 - Generate correction commands depending on this measurement (Up, Down)
- Correction commands control the charge pump (Icp) pumping/sinking current into/from the filter capacitor, varying the control voltage for the Voltage Controlled Oscillator (VCO)
 - Gradually, the timing error of the two signals at the inputs of the PFD would vanish (ideal locked condition)

Frame

40-Bits

120-Bits

2,5,8,..

1.4.7..

t'_{master}

f_{bit/3}

3.6.9...

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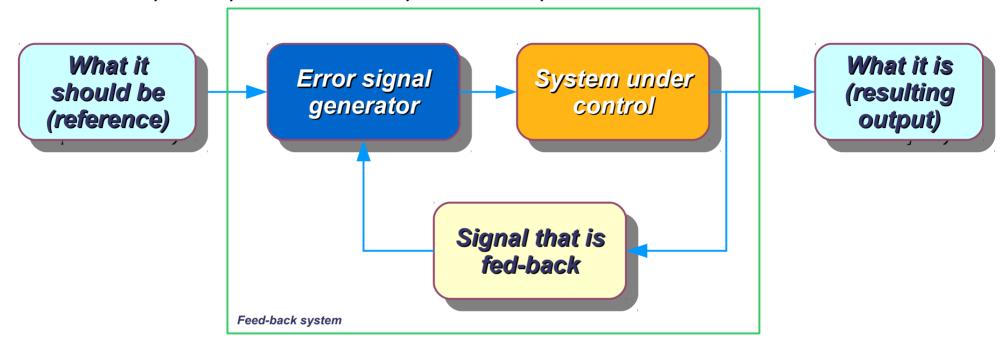
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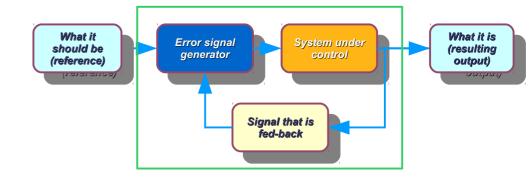
Feed-Back

Actually a very familiar concept from daily life



- Aim, is decreasing the difference (the error signal) between the reference and the output
- How ? For each cycle:
 - → A **portion of the output** is fed-back. Make the system be **sensitive** to a portion of what it outputs
 - → Measure the difference between the reference and what is fed-back (only a portion of the output)
 - → Depending on the difference, an **error signal** is generated which in turn causes a **correction step** to be taken **controlling the system** under control
 - Repeat the cycle

Feed-Back Actually a very familiar concept from daily life



- Whistling or playing an instrument ?
 - → How do I know what I play is "Do" but not "Re"?
 - → Does it make sense to say "I whistle better than you"?
 - → What happens when I try to find the right guitar solo for an existing song?
- Drinking a glass of water ?
 - Adjust the angle & position of the glass accordingly to keep the water flow as it is necessary?
 - → Remember the childhood: sometimes the water gets dropped to the ground accidentally (What is the **failure mechanism**?)
- Walking and biking ?
 - → How do I decide the frequency of my steps not to fall down or to be able to reach somewhere?
 - What about walking or biking when drunk? (What is the failure mechanism?)
- Ruling a country ?
 - → Can "referendum" be a term borrowed from the control theory?
 - → How come politicians of the same ideology can decide in substantially different manners? < Questionably ignoring corruption :D >

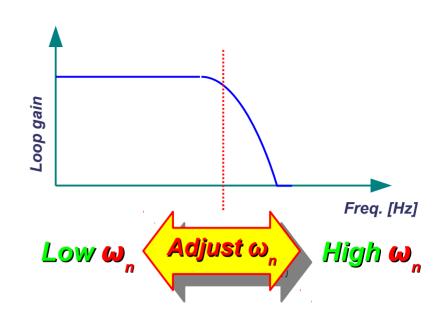
Feed-Back What it What it is System under Error signal should be (resulting generator control (reference) output) Natural frequency concept Signal that is fed-back Corner 100% Correct answers [%] Success $T(s) = \frac{\omega_n^2(\tau s + 1)}{\frac{s^2}{N} + 2\xi s \frac{\omega_n}{N} + \frac{\omega_n^2}{N}}$ Decreasing success How frequent the questions are asked [Hz] ω

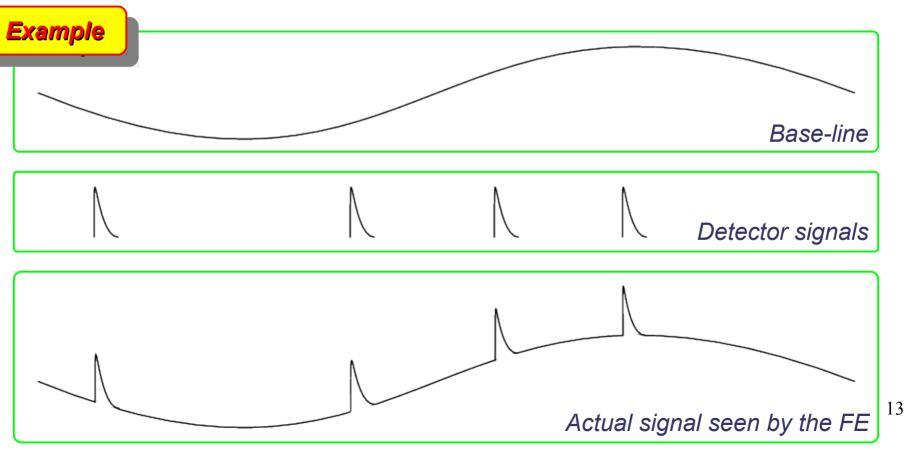
- An imaginary system answering questions asked continuously
- Plot (both logarithmic scale) the success level within a certain time window as a function of frequency of questions asked (transfer function)
- If the questions are asked slow enough, the system answers all, thus 100% success level
- Once the questions start to be asked faster, the system starts failing answering all, thus transfer function begins going down
- Corner is at the natural frequency of the control loop where the system starts impairing significantly

Feed-Back

Choosing for what to be sensitive

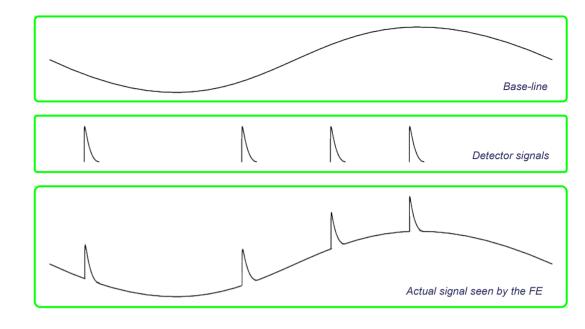
- Low ω_x → Sense slow variations
 - Loop acts on slowly varying signals
 - → Narrow bandwidth slow loop
- High ω_n → Sense fast variations
 - → Loop acts on rapidly varying signals
 - → Wide bandwidth fast loop

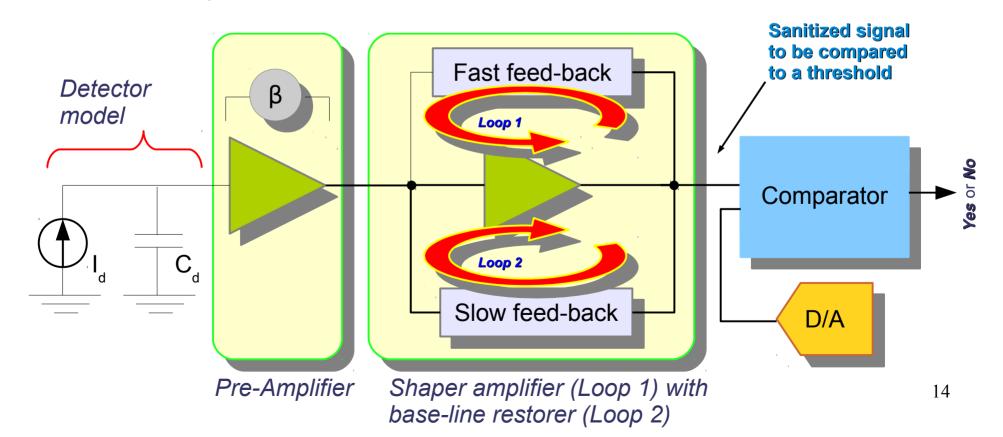




Example Binary read-out

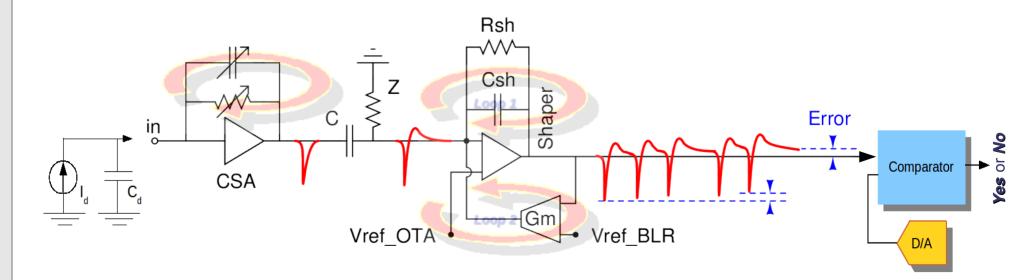
- Requires stable base-line
 - Which varies slowly
 - → A narrow loop bandwidth is needed (Loop 2)
- Requires a fast signal shaper
 - Which varies rapidly
 - → A wide bandwidth is needed (Loop 1)





Real-World Example Binary read-out for time-over threshold measurement

- **Random** detector **pulses** with a few MHz frequency; then...
 - How fast is the fast loop?
 - How slow is the slow loop?
- Depending on the read-out **speed** and the operating environment, parameters are optimized
 - → Natural frequencies and gains of the loops, rise/fall-times, etc.
 - Settling behavior, radiation tolerance, damping ratio, power, etc.
 - Circuit footprint, robustness, redundancy, channel efficiency, etc.

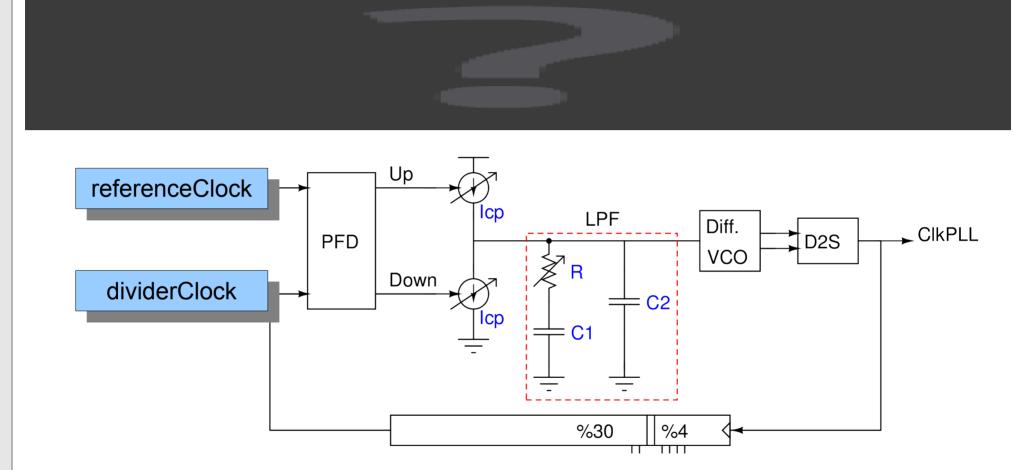


(פווופזפאפ פוזסוזוווזווסס)

What it

What it is

Simulation Movie Quiz Remember the PLL

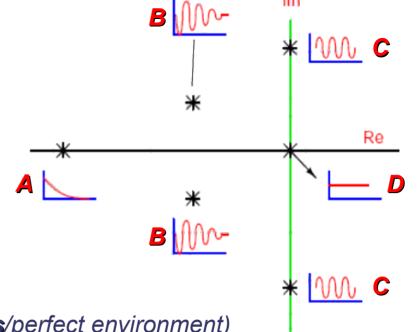


- Slow down the VCO, if it is too fast with respect to the reference
- Speed up the VCO, if it is too slow with respect to the reference

Simulation Movie Quiz Different loop behaviors

See the movies and associate the behavior to the poles on the s-plane (complex plane)

Use your intuition



? - Slow-loop with low damping ratio (noiseless/perfect environment)



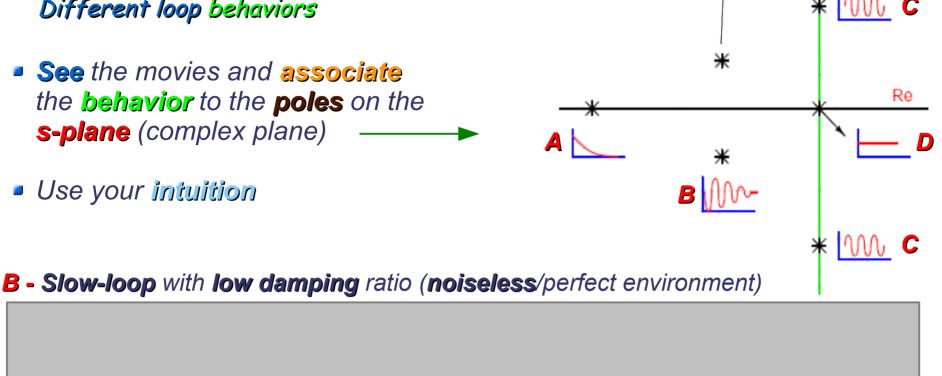
? - Slow-loop with low damping ratio (noisy environment)

Simulation Movie Quiz

Different loop behaviors

See the movies and associate the behavior to the poles on the s-plane (complex plane)

Use your intuition



? - Fast-loop with high damping ratio (noiseless environment)

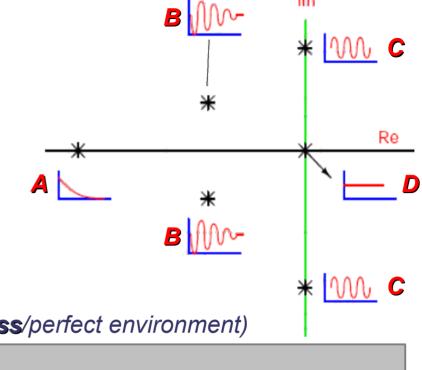
? - Slow-loop with low damping ratio (noisy environment)

Simulation Movie Quiz

Different loop behaviors

See the movies and associate the behavior to the poles on the s-plane (complex plane)

Use your intuition



B - Slow-loop with **low damping** ratio (**noiseless**/perfect environment)

A - Fast-loop with high damping ratio (noiseless environment)

? - Slow-loop with low damping ratio (noisy environment)

Back to the big picture

If the PLL fails, then nothing works !..

- In case the loop parametrization is wrong:
 - → PLL can not deliver a proper clock
 - → No phase/frequency locked ClkPLL signal
 - Ignored LHC clock, no synchronization
 - → SER fails

RefClk

- Some of the bits get lost or duplicated
- → High jitter leading to closed eye diagram

Icp

LPF

R

C1

%30

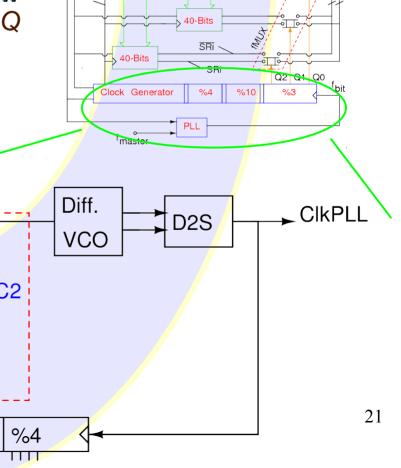
→ RO fails delivering the data from FE to DAQ

Up

Down

No DAQ → Fatal error !...

PFD



120-Bits

2.5.8...

1,4,7..

40-Bits

DAQ

r_{master}

Load

f_{bit/3}

3.6.9...

FE FE

FΕ

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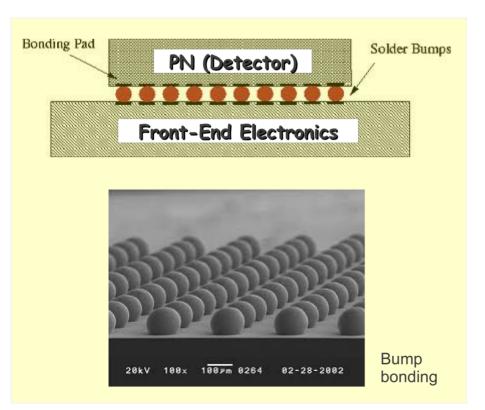
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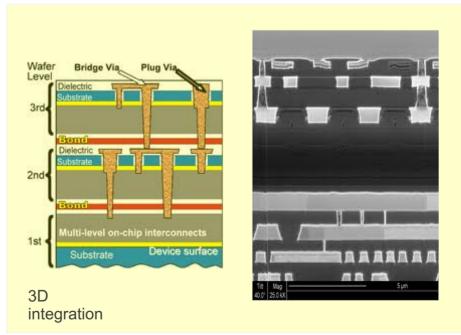
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An Example

Pilatus System: A hybrid of "sensor + electronics"

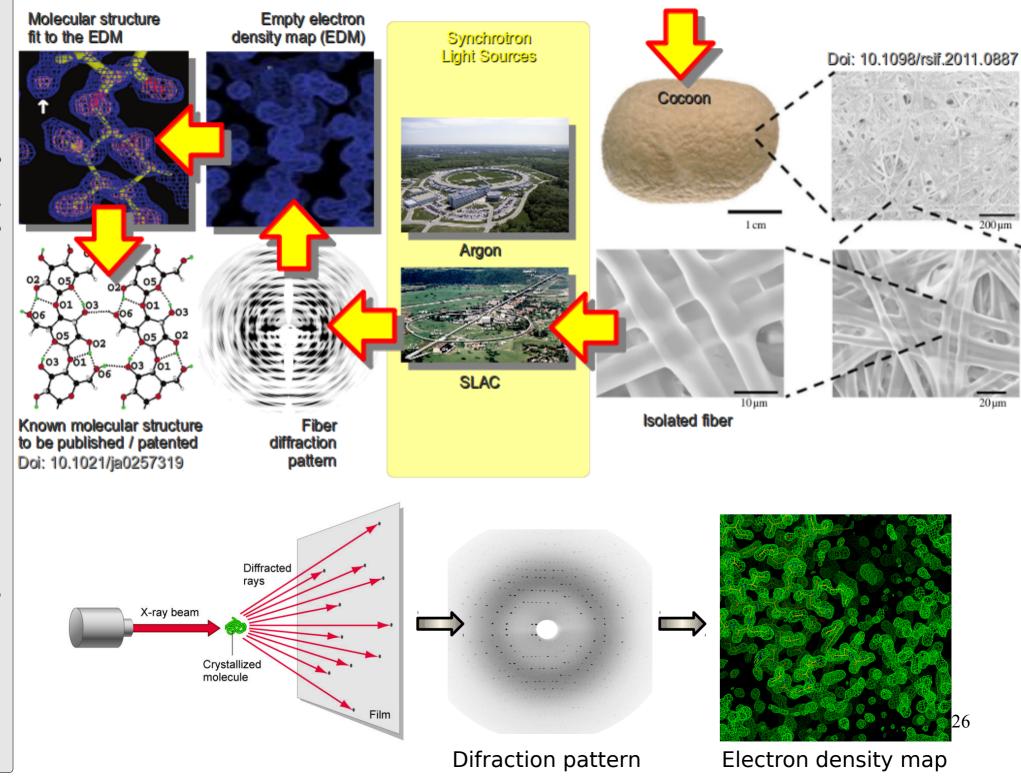
- "The development at PSI is driven by the design of the pixel detector for the CMS (Compact Muon Solenoid) experiment at the planned Large Hadron Collider (LHC) at CERN." (Ref: http://pilatus.web.psi.ch/publications.htm)
- Hybrid: fully depleted detector sitting on top of the front end electronics, reading out the detector, integrated within each of the pixels
- Composed of the detector, charge-sensitive preamplifier, shaper, comparator and counter





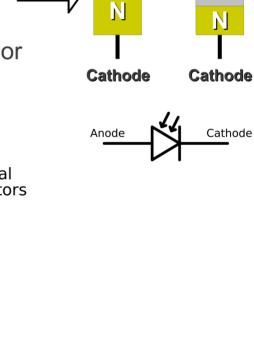
X-rays on Detector

Cose S Energy



First interaction with the photons (and/or particles)

- Impossible to cover all
 - There are **many types** and even **many more examples** of particle detectors
- Therefore limited
 - Just a few types and examples should be enough, given the limited time
- "Seeing" the photons → photodetector != photon counter
 - Photo-detectors: generate an analog level (i.e. I or V) as a function of "light" intensity (e.g. PN and PIN structures)
 - Photon counters: count individual bursts of photon bundles or single photons (e.g. PMTs and avalanche diodes)

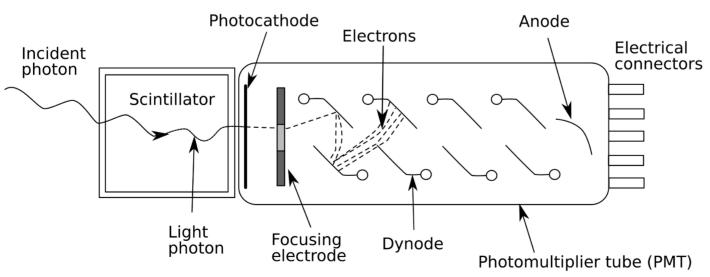


Anode

P

Light

Anode



First interaction with the photons (and/or particles)

- Photo-detectors: generate an analog level (i.e. I or V) as a function of "light" intensity (e.g. PN and PIN structures)
- Two modes of operation:
 - Photo-voltaic mode
 - Depleted region is exposed to light and voltage is measured, with no bias
 - Photo-conductive mode
 - Exposed light generates a current flow, under reverse-bias
- Some important features:
 - Responsivity (I/P optic)
 - Active area
 - Max photo current (limited by saturation)
 - Dark current (in photoconductive mode)
 - **Bandwidth** (rise, fall times)
 - ÷ ...
 - **→** ...

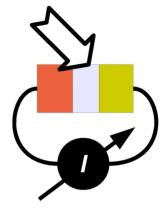


Photo-voltaic mode

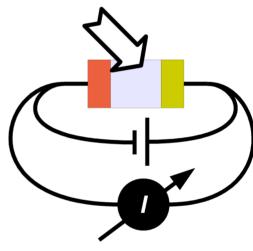
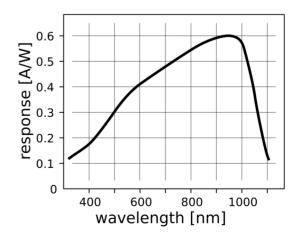
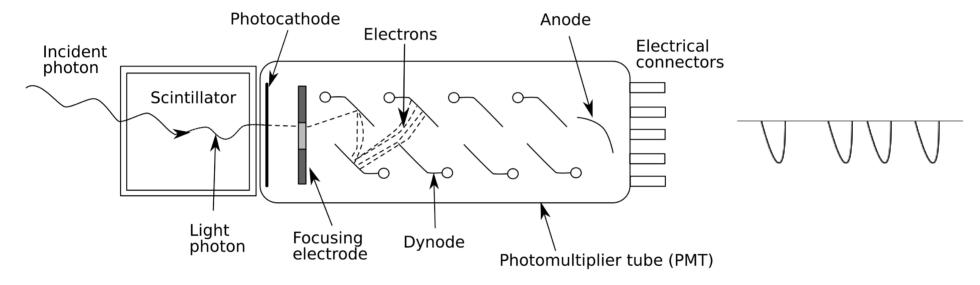


Photo-conductive mode

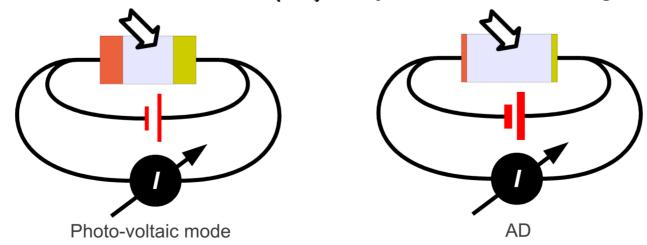


First interaction with the photons (and/or particles)

- Photon counters: count individual bursts of photon bundles or single photons (e.g. PMTs and avalanche diodes or SPADs)
 - Photomultipliers: if photons arrive at the detector with low-enough frequency

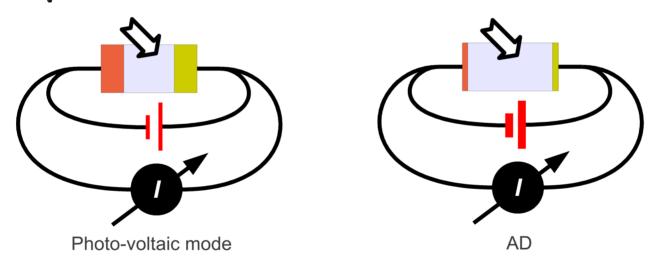


→ Single Photon Avalanche Diodes (AD): PN junctions under strong reverse-bias



First interaction with the photons (and/or particles)

- Photon counters: count individual bursts of photon bundles or single photons
 (e.g. PMTs and avalanche diodes or SPADs)
 - → Avalanche Diodes (AD) are PN junctions reverse-biassed just below the break-down voltage such that single-photon induced electrons are accelerated within a few µms



- Single-Photon Avalanche Diodes (SPAD) are PN junctions reverse-biassed just above the break-down voltage. When a photon strikes, bias voltage is droped down below the threshold (but not to break-down) for a short time (e.g. 100 ns) by carefully designed electronics to recover, such that the detector is ready for the next detection
- SPADs can also be used for time-resolved techniques as they can provide information on photons time of arrival in addition

Position Sensitive Architecture

First interaction with the photons (and/or particles)

- Detect particles with the sensitivity of where they land; two main paradigms:
 - Resistive charge division on a single detection element:

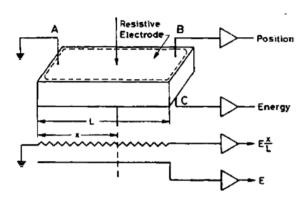
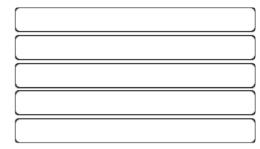


Fig. 10.14. Layout of a one-dimensional continuous position-sensitive detector using resistive charge division. A simplified equivalent circuit is shown below

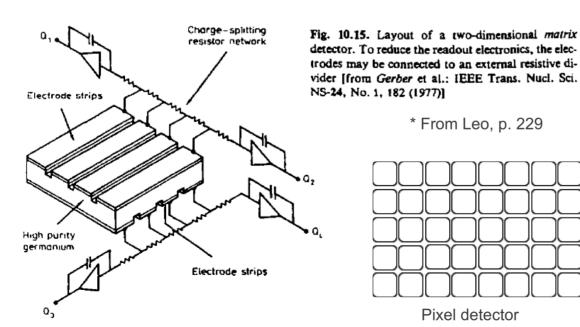
* From Leo, p. 227

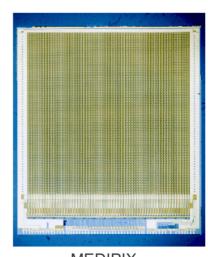
$$Position = \frac{B}{C}$$



A hybrid: Discrete array of resistive charge division

Discrete array of individual detection elements:

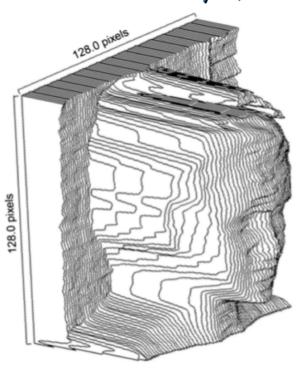




MEDIPIX

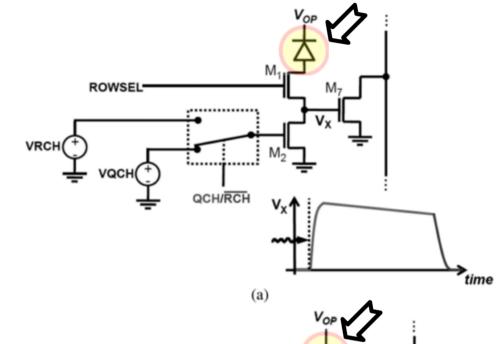
Time Resolved Architecture

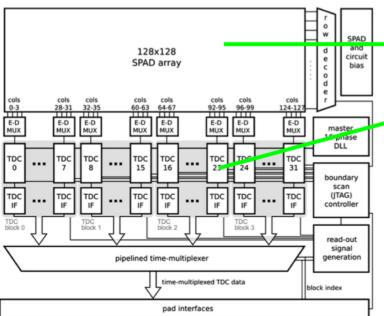
Flash the sample, start a timer, acquire single photons and their arrival times

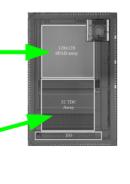


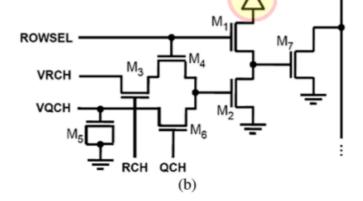


A 128 128 Single-Photon Image Sensor, With Column-Level 10-Bit Timeto-Digital Converter Array, IEEE JOURNAL OF SOLID-STATE CIRCUITS, VOL. 43, NO. 12, DECEMBER 2008







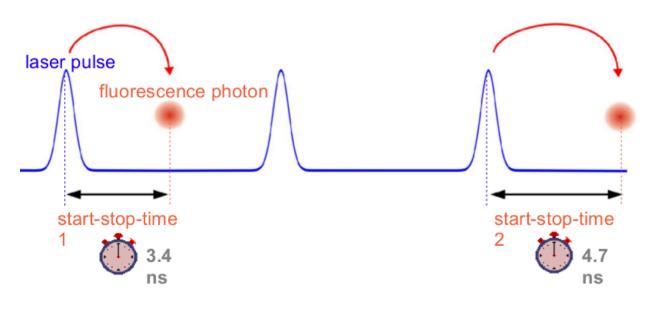


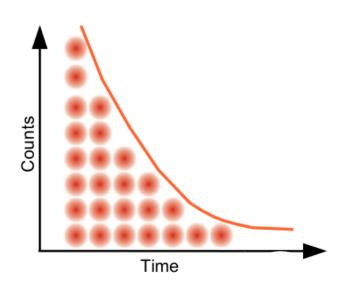
- Like an ordinary pixel detector (e.g. CCD)
- However measures "time" instead of "color" (e.g. TPC)
- Generates 3D and color-less images

Time Correlated Architecture

First interaction with the photons (and/or particles)

- Measuring the profile of a fast (e.g. fluorescence, from ps to ns) and/or weak decay is tricky
- Recovering not only the lifetimes but also the decay shape requires the decay to be represented by at least 10s of samples
- The idea:
 - → Meet the single photon counting condition(?)
 - → Make your detector fast
 - → Decrease the number of **photon creation** at the source
 - **Excite** the system to be probed (e.g. via a laser)
 - Count photons per reference excitation
 - Fill a histogram to visualize decay profile





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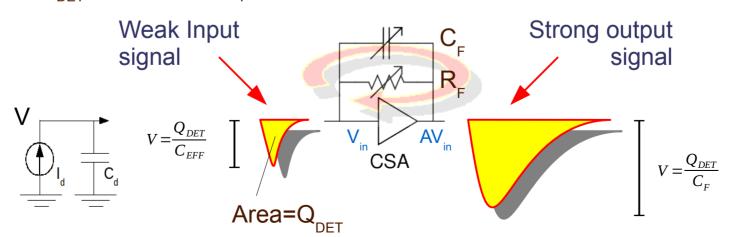
Pre-Amplifier The first store of the inte

The first stage of the interpretation

- Standardized experimental techniques over time
- Our discussion on intuitive & descriptive level
- $T = \frac{V_{OUT}}{V_{IN}} = \frac{A}{1 + AB}$
- sage: T(A, B) = A/
 (1+A*B)
 sage:
 T.limit(A=infinity)
 (A, B) |--> 1/B

out

- Three types of pre-amplifiers:
 - → Voltage sensitive: usually not preferred due to the fact that, for a given amount of charge generated by the detector (Q_{DET}), the output voltage of the detector (V) is a function of the effective capacitance (C_{EEE}) of the detector which is variable
 - Current sensitive: not preferred because they are suitable to be used with low impedance devices, however radiation detectors have usually high impedance
 - Charge sensitive: preferred type because its output is only a function of the charge (Q_{DET}) and a fixed C_E, provided that amplifier gain is sufficiently high



Amplifier Basic How to amplify something

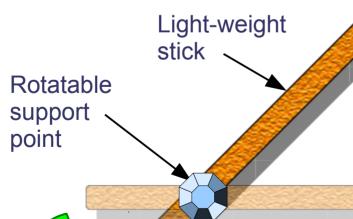
We want a small change in the input to cause a big change at the output

→ The **reason** it is called an amplifier

However in a real circuit, the input signal **dies** out, therefore:

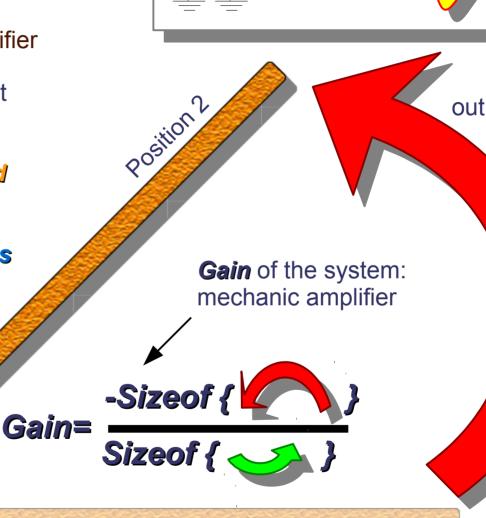
Output signal is a re-generated larger "clone"

Output can have other features that the input did not



Support

(the amplifier)



CSA

Weak

input

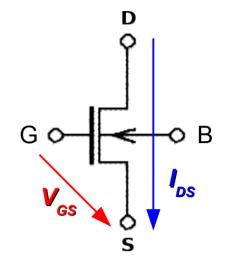
signal

Strona

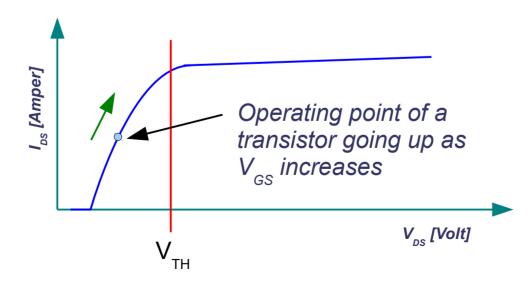
output signal

Transconductance - g_m Figure-or-merit for a transistor

- Define a figure-of-merit (FOM) for a single nMOS
 - How well a transistor converts voltage into current
 - From input V_{GS} to output I_{DS}

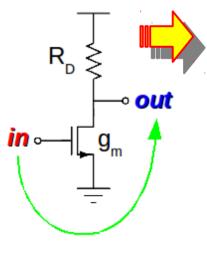


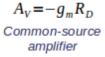
$$g_{m} = \frac{dI_{DS}}{dV_{GS}} = \frac{2I_{D}}{V_{GS} - V_{TH}}$$

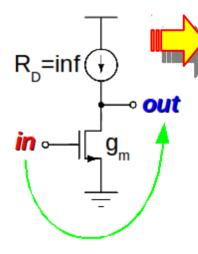


Basic CMOS Amplifier Single-stage common-source amplifier and its evolution into a complete circuit

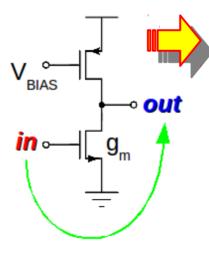
- Sink current through R_n
 - → As in increases, out decreases (faster)
- -g_R suggests that we should increase the load impedance to have higher voltage gain
 - An ideal current source has infinite impedance
- A current mirror is a practical current source
 - Simply a transistor biased as a current source
- Transconductance (g_) increases with current
 - Supply additional current to the gain device to have higher gain



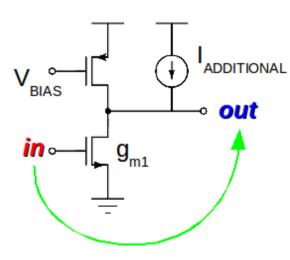




 $A_{\rm V} = -g_{\rm m} r_{\rm o}$ Common-source amplifier



 $A_{V} = -g_{m}(r_{o1}||r_{o2})$ Common-source amplifier

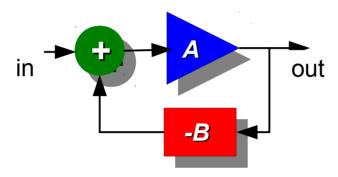


$$A_V > -g_m(r_{o1}||r_{o2})$$

Common-source amplifier with current source load featuring higher gain due to increased current

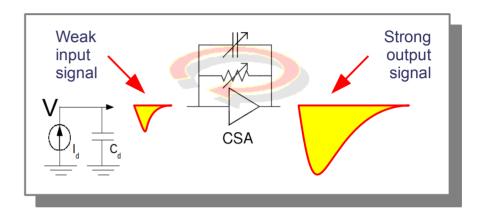
Basic CMOS Amplifier Single-stage common-source amplifier and its evolution into a complete circuit

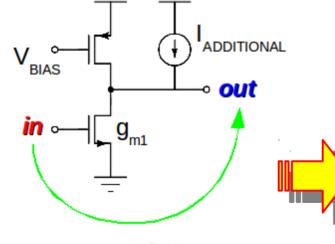
- Add the feedback network C₂ & R₂ forming the B such that
 - For high enough A_v, closed loop gain is 1/B



$$T = \frac{V_{OUT}}{V_{IN}} = \frac{A}{1 + AB}$$

$$\begin{array}{c} sage: T(A, B) = A/\\ (1 + A * B) \\ sage: \\ T. limit(A = infinity) \\ (A, B) / --> 1/B \end{array}$$



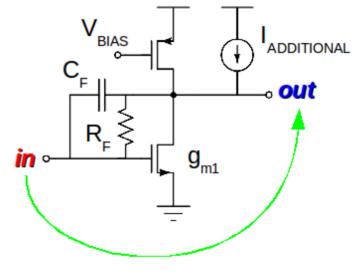


$$A_{V} \! > \! -g_{\scriptscriptstyle{m}}\!(r_{\scriptscriptstyle{ol}}\!||r_{\scriptscriptstyle{o2}})$$

Common-source amplifier with current source load

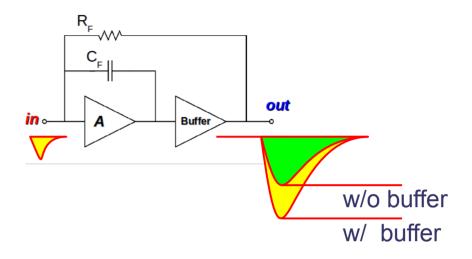
featuring higher gain due to increased current

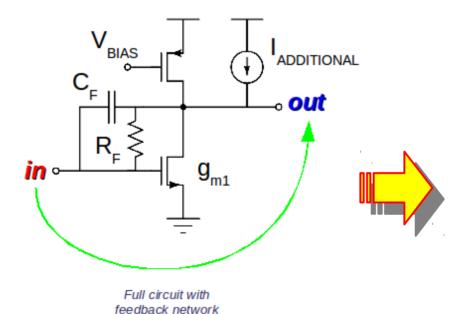
Full circuit with feedback network

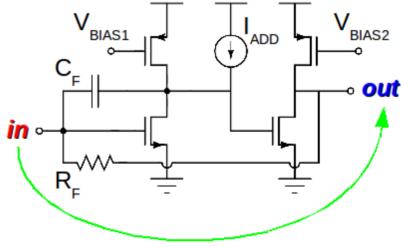


Basic CMOS Amplifier Avoid loading effect of the resetting resistor

- Problem: while c_i is charged, R_i resets at the same time
 - **Lowering** the voltage gain, therefore:
 - Loading effect of the feedback resistor should be avoided
 - → Integration and resetting should be decoupled
 - Employing a **buffer** is one of the possible solutions





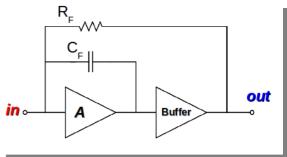


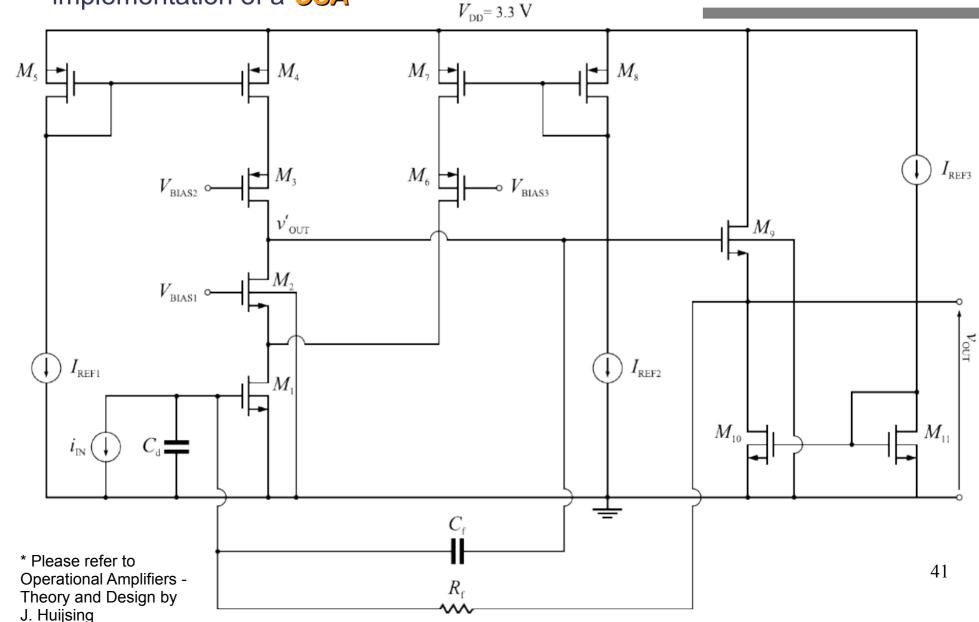
Full circuit avoiding resistor loading effect

Pre-Amplifier

Full circuit (currently in use at a RICH detector)

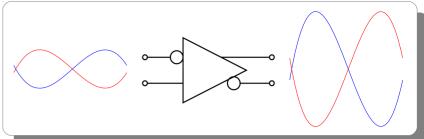
 Actual CMOS device-level implementation of a CSA

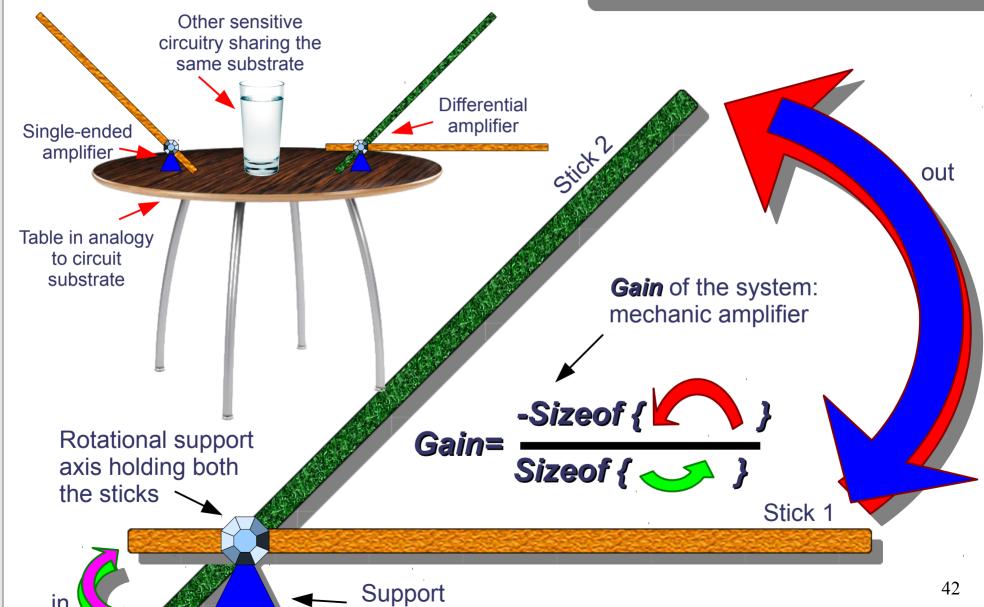




Differential Amplifier

Generating less noise (also for others) in the cost of more complex design

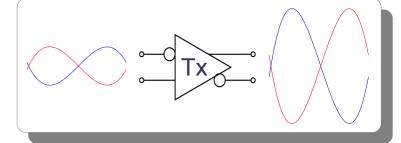




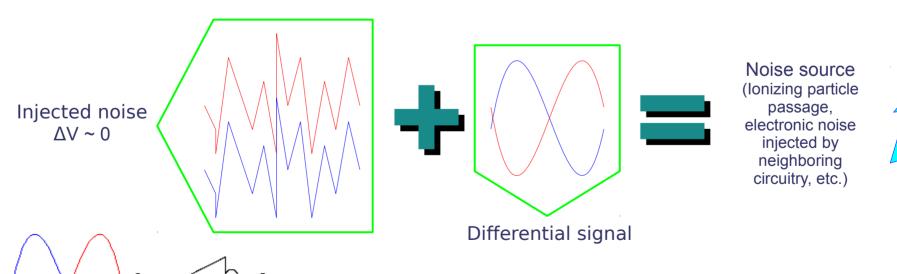
(the amplifier)

Differential Signaling

Rejecting noise



- The information Tx generates is in the difference
 - Signal creates complementary current images on the substrate
 - Generating less noise for neighboring circuitry
- Rx compares the voltage levels of the pair
- Any noise source should affect both of the lines similarly
 - Generating almost identical transients on both of the wires
 - → Pair wires are close to each other
- Practically high noise rejection is feasible

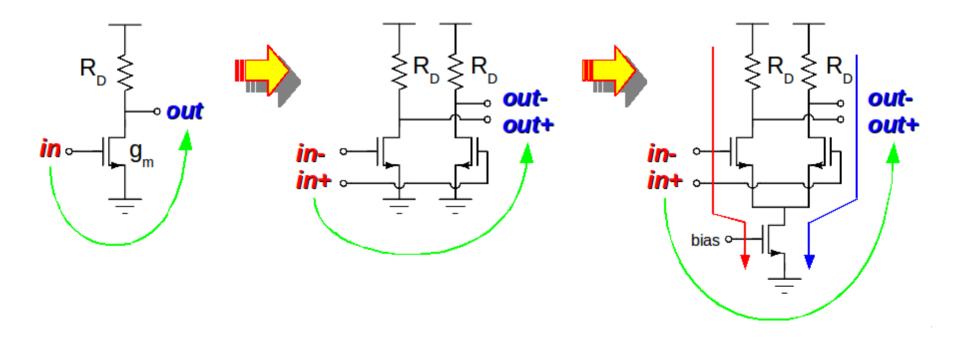




Metal wires

Differential Signaling Differential gain stage

- Sink current through R_D
 - → As in increases, out decreases (faster)
- Double the structure to act on both the signals
 - Drawback: signals can be identical (no differential information)
- Steer the current either through one inverter or the other
 - → Transition at the input changes the path through which the current is steered
 - → Unless metastable, the amplifier has always differential information at he output



Introduction to the Design of Full-Custom Front-End & Data Transmission ASICs*

Table of Contents

The Big (but Brief) Picture

- Briefly front-end FE
- Briefly read-out RO
- Briefly serializer SER
- → Briefly phase-lock loop PLL

Feed-Back Concept

- → A qualitative introduction
- Natural frequency concept ω
- Real-world examples:
 - Binary read-out
 - Time-over threshold
- Adjusting/optimizing loop behavior
 - Damping ratio

Reminder on Detectors

- Photodetectors vs photon counters
- **→ Position-sensitive** detectors ¶NEW
 - Resistive charge division
 - Discrete array of elements
- Time-resolved detection

Detector Front-End ASICs

- → Pre-Amp: basic idea V_{out} / V_{IN}
- → Transconductance of a transistor g_m
- Evolving a single-stage amplifier into a real-world application

Processing Technology

- Transistor switch A masterpiece
 - Lithography
 - → Formation of an **nMOS** transistor
- VLSI design flow
 - Parasitic extraction
- Real-world ASIC examples

Radiation Tolerance Issues

- Definitions:
 - Single event upset, analog single event transient, latch-up
- Simulating radiation effects on analog circuits

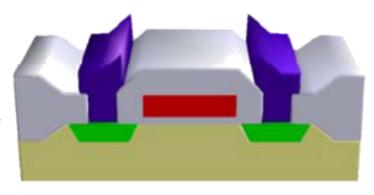
* Application Specific Integrated Circuit

Semiconductor Switch - Transistor

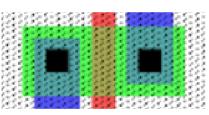
A masterpiece

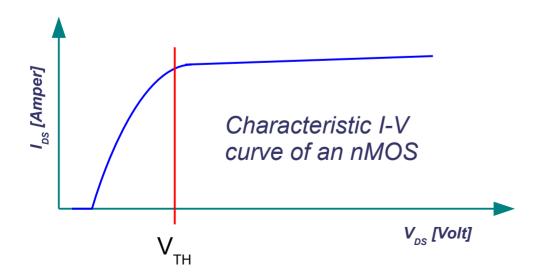
Current conduction between <u>Drain-Source</u>
 as a function of <u>Gate-Source</u> voltage

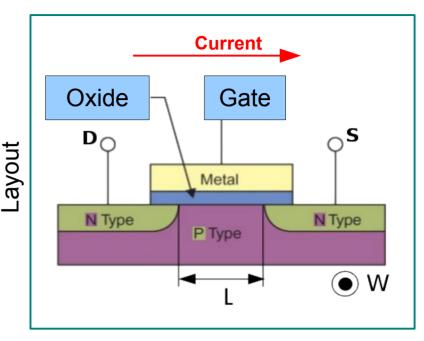
3D view of a single MOS transistor

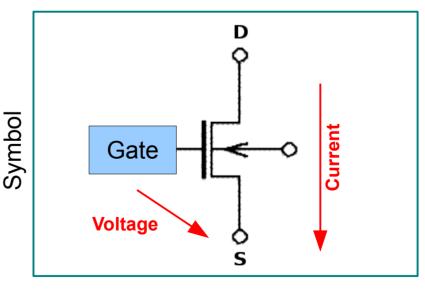


A single MOS transistor as drawn by a designer





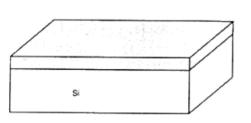




Lithography

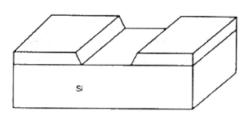
The art of light drawing

- A real microelectronic circuit is like a city composed of many layers
- A specific lithographic mask is needed for each layer to be created
- As an example we will create a "line" on an oxide layer



Initial state



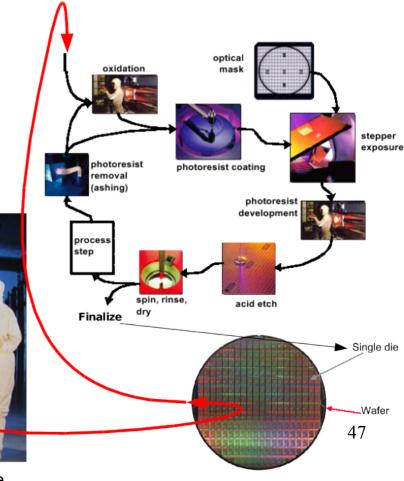


Target

The *ingot* to be sliced into *wafers*

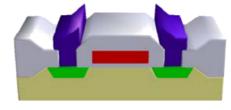


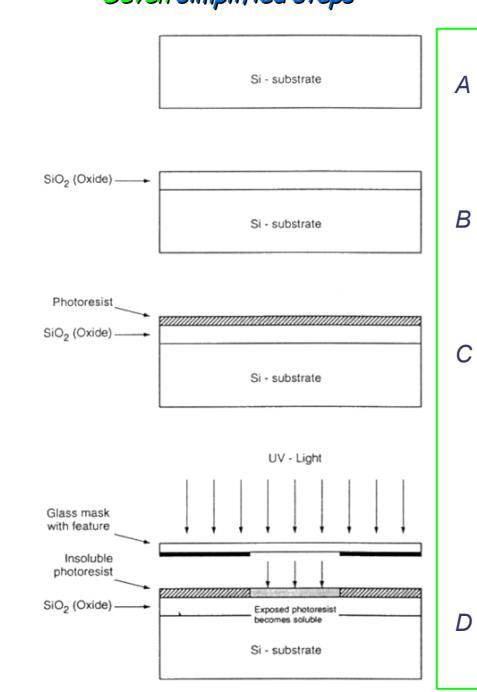


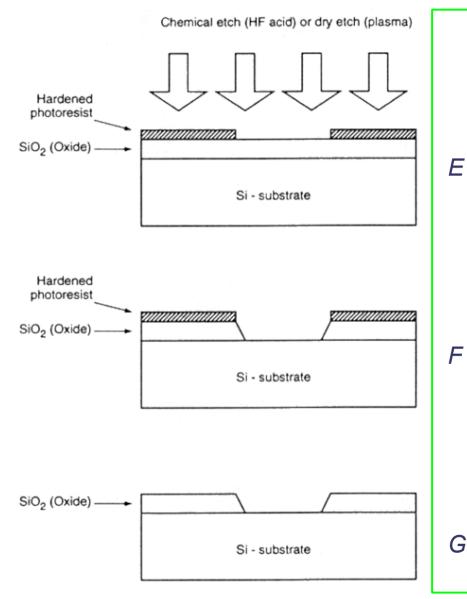


^{*} Please refer to Semiconductor Devices: Physics and Technology by S. M. Sze

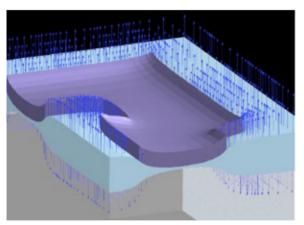
Just to draw a single line Seven simplified steps

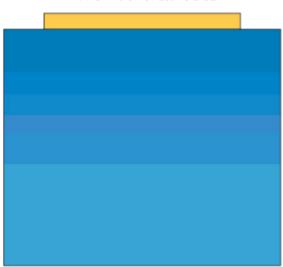




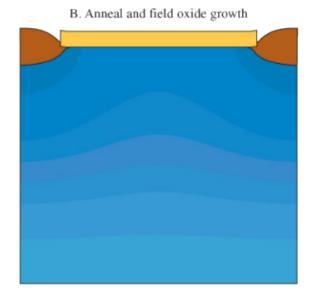


Fabrication of an nMOS Simplified steps - Part I

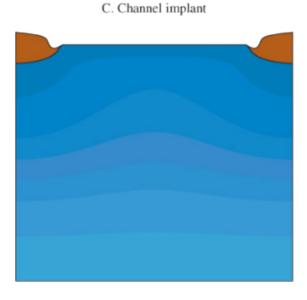


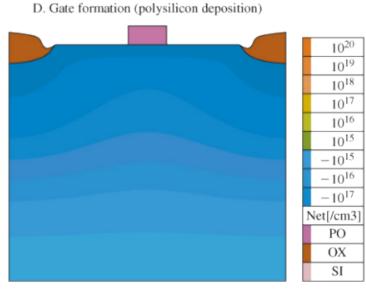


A. Definition of active area



- **Nitride** defines the active areas
- FOX is developed
- Nitride is removed by a solvent
- Polysilicon is deposited

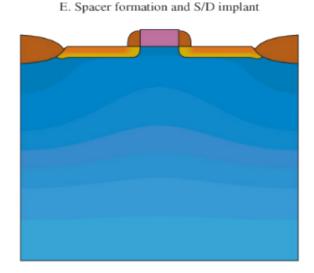


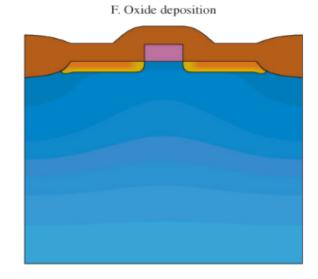


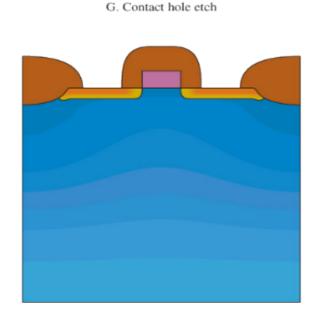
49

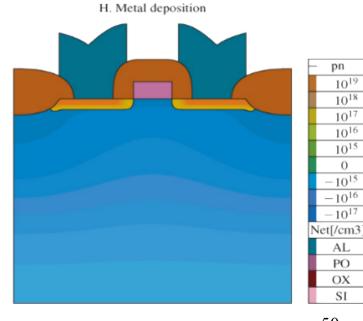
Fabrication of an nMOS Simplified steps - Part II

- Spacer & active field formation
- Dep. of **SiO**,
- **Etch**ing contact holes
- Metal dep.







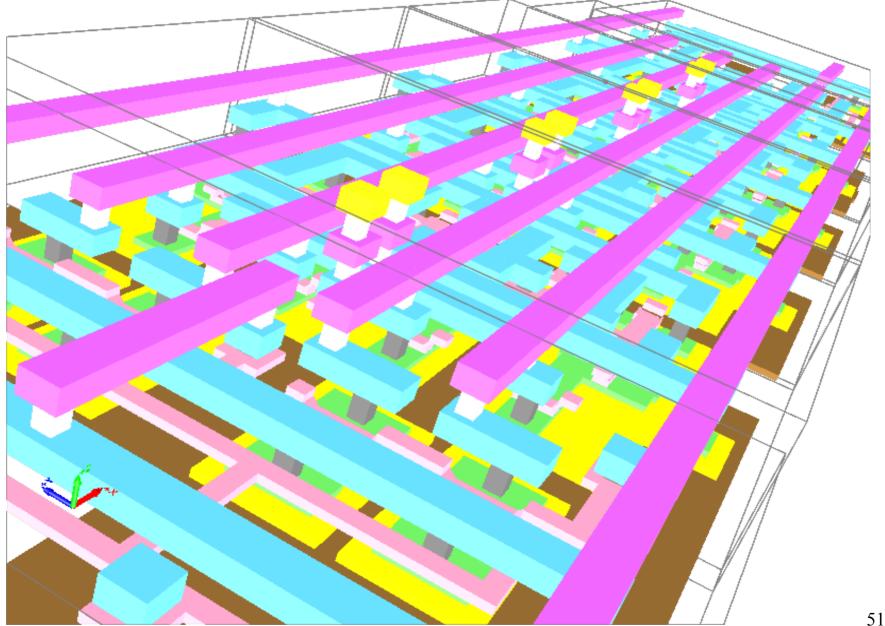


 10^{19} 10^{18} 10^{17} 10^{16} 10^{15}

 -10^{16} -10^{17}

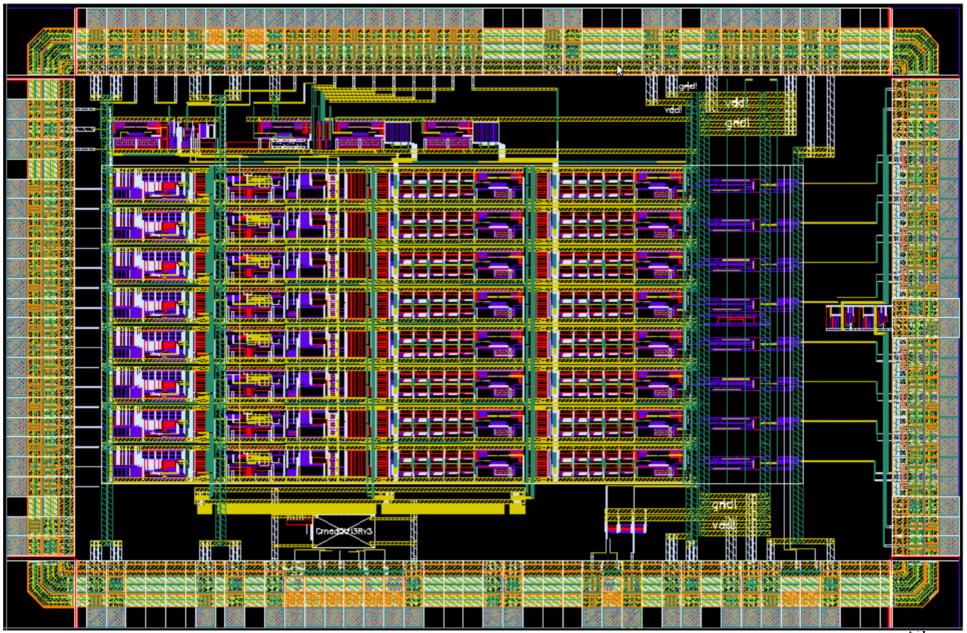
> AL PO OXSI

How many layers do you see? A process repeated a few hundred times



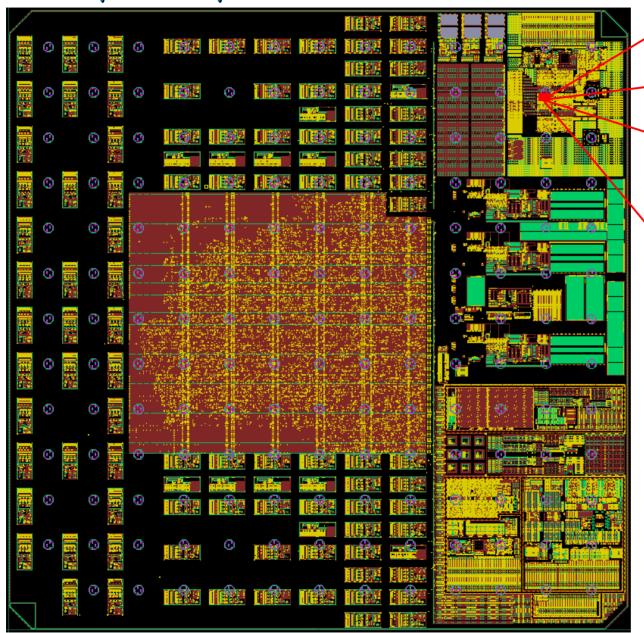
A ring-type oscillator

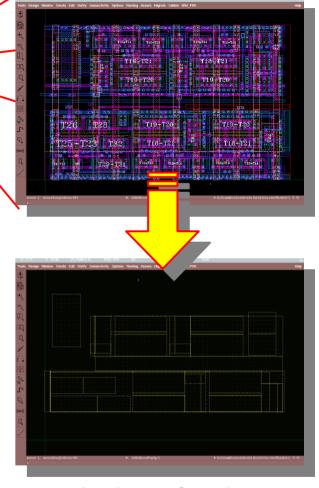
How many layers do you see? A process repeated a few hundred times



The CAMD front-end ASIC designed for RICH-I detector of COMPASS experiment at CERN. (350 nm CMOS).

How many layers do you see? A process repeated a few hundred times





A sub-set of masks forming the above block (Animated GIF image)

The first prototype of the SER-DES ASIC for the GBT13 chip-set under development for the Super-LHC at CERN. (130 nm CMOS)

VLSI Design in Practice

Daily life of an ASIC designer

 2λ

 2λ

 2λ

 2λ

 2λ

 2λ

 1.5λ

 1.5λ

Interface between process scientist and designer

Focus on reliability and increased manufacturability

T(s) =	$\omega_n^2(\tau s + 1)$
	$\frac{s^2}{N} + 2\xi s \frac{\omega_n}{N} + \frac{\omega_n^2}{N}$

D2S Converter Bias

[5.3	
5.1	5.2 5.2 5.4
6.2	

9.2.a

9.1

9.2.a

7.2.a

7.1	Min. width	3 λ
7.2.a	Min. spacing	3 λ
7.3	Min. overlap of any contact	1λ

T 7		1
V 1	120	- 1

Metal 1

Contact

Exact contact size

Min. poly overlap Min. spacing

Min. spacing to gate

Exact contact size

Min. active overlap

Min. spacing Min. spacing to gate

8.1	Exact size	2λ
8.2	Min. spacing	3λ
8.3	Min. overlap by metal1	1 λ
8.4	Min. spacing to contact	2λ
8.5	Min. spac. to poly or act. edge	2λ

Metal2

(*)

9.1	Min. width	3 λ
9.2.a	Min. spacing	4 λ
9.3	Min. overlap to via1	1 λ

Not Drawn

Schematic entry

Specifications

Layout

Simulation

Design Rule Check

Parasitic Extraction

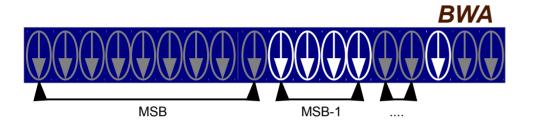
Layout Versus Schematic check

Post-Layout Simulation

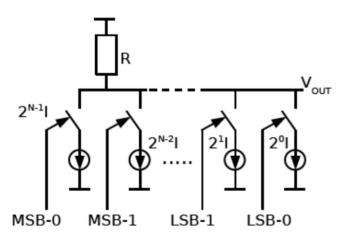
Architectural Choice

Quantitative comparison between different approaches

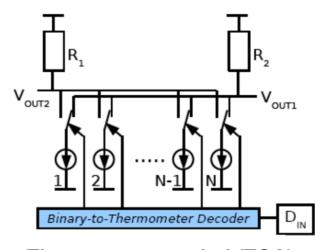
- → A 10-Bit current-mode D/A converter
- Two possible architectures; have to choose one
- Need for qualitative comparison: MC is a must



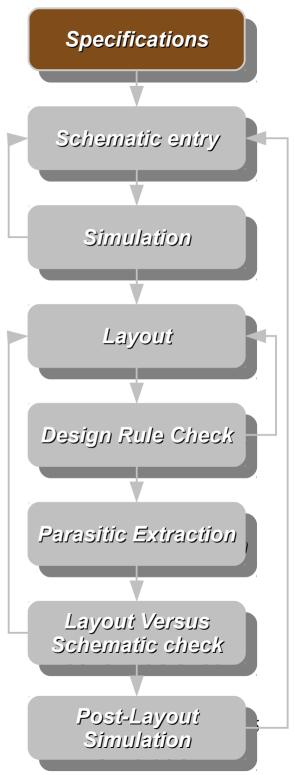




Binary weighted (BWA)

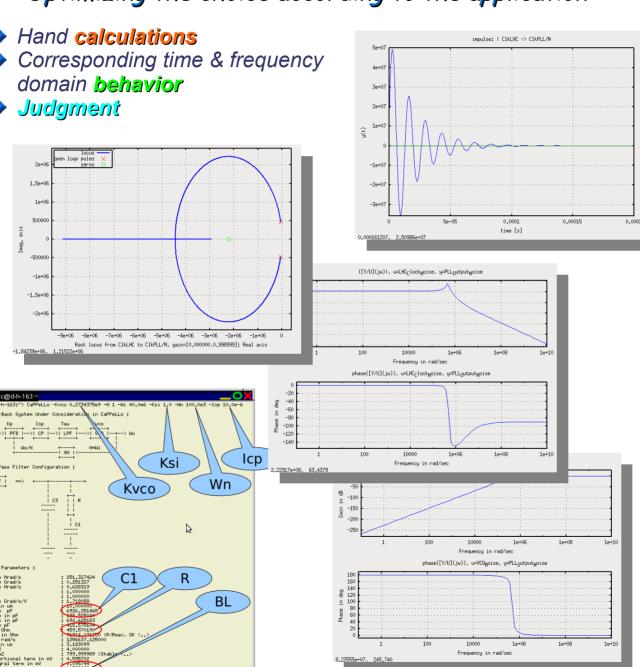


Thermometer coded (TCA)

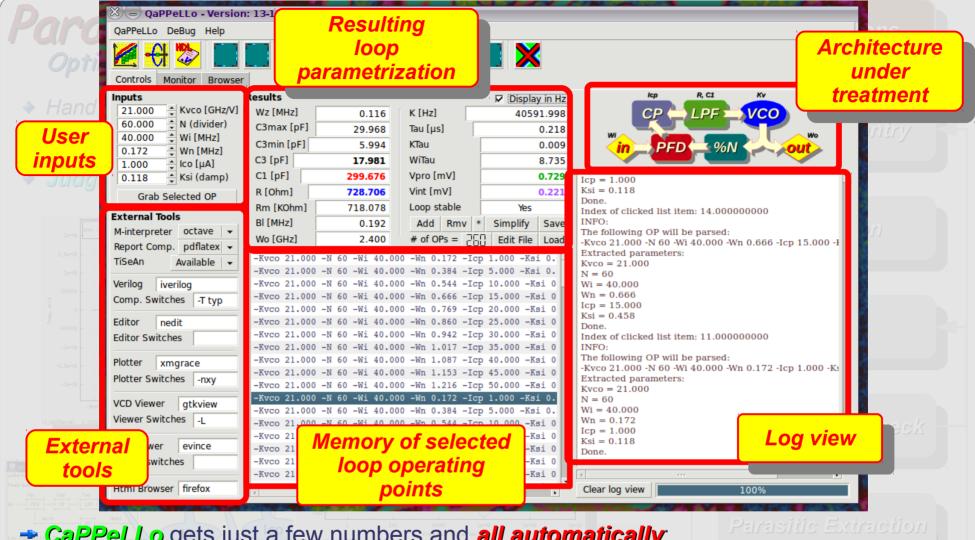


Parametrization

Optimizing the choice according to the application

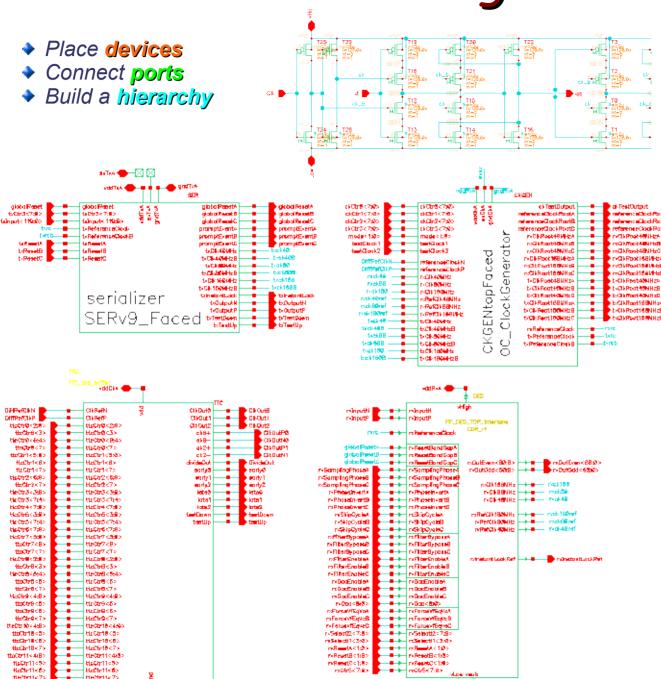


Specifications Schematic entry Simulation Layout Design Rule Check Parasitic Extraction Layout Versus Schematic check Post-Layout Simulation



- CaPPeLLo gets just a few numbers and all automatically.
 - Calculates loop parameters and generates the stability map for comparison
 - Calculates frequency domain loop response as
 - Bode and root locus plots, step & impulse responses, noise transfer functions, etc.
 - Generates the verilog model of the architecture with the selected parameters
 - Compiles and runs the verilog model, displays the wave forms
 - Analyzes the jitter data generated during the this simulation
 - Searches for chaos by means of time series analysis and creates attractors, etc.
 - Generates a report summarizing all above actions

Schematic-Level Design

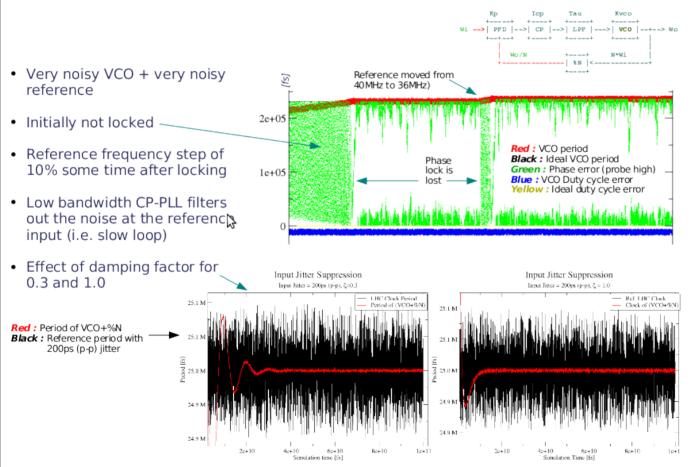


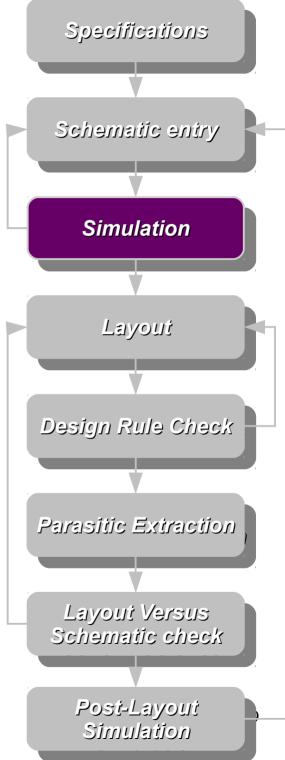
- ⊠——— in Cha

Specifications Schematic entry Simulation Layout Design Rule Check Parasitic Extraction Layout Versus Schematic check Post-Layout Simulation

Simulation

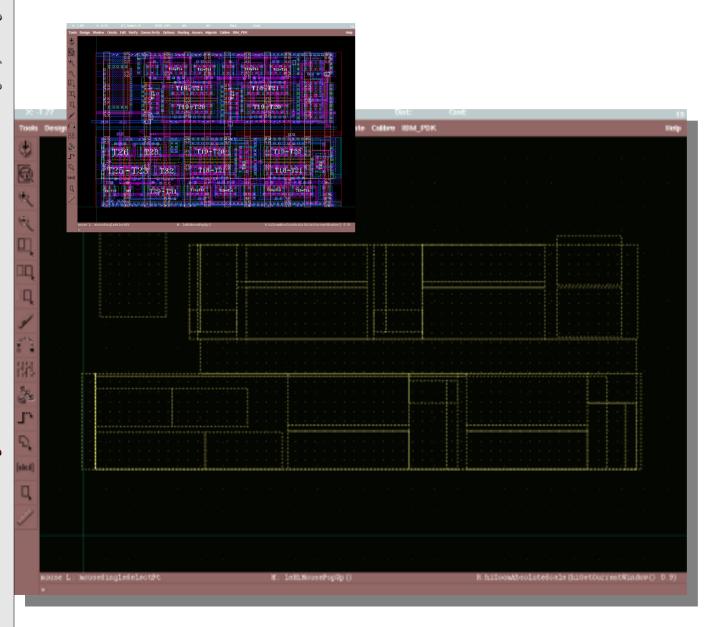
- Model-based time-step simulations (HDLs, MatLab, Octave, Cadence, etc.)
- → Transistor-level SPICE simulations (Spectre, UltraSim, etc.)
- Radiation simulations (Process simulators, Spectre, etc.)

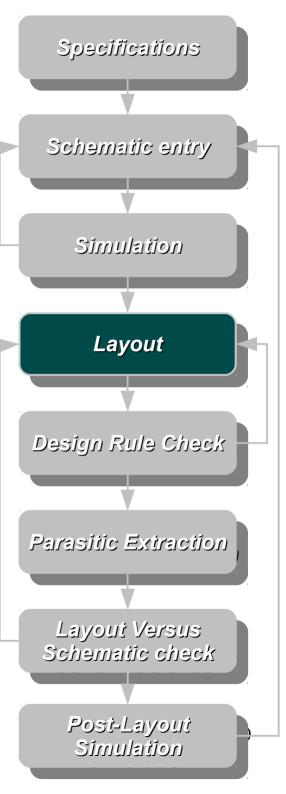




Layout

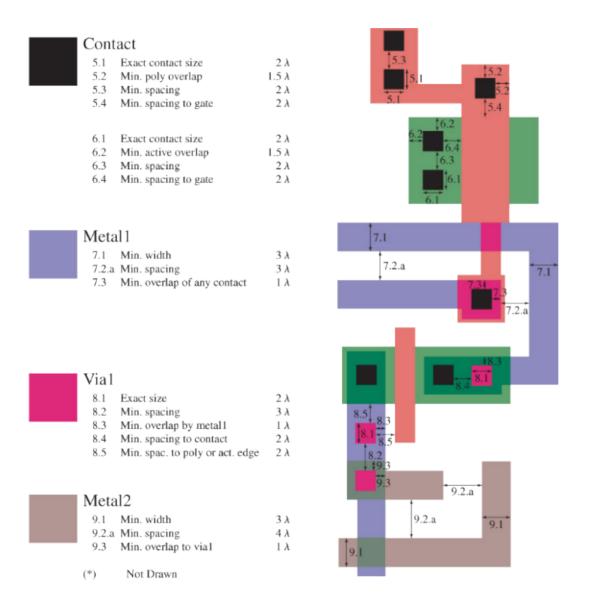
- Lithographic masks are designed
- Actual representation of a circuit on the die

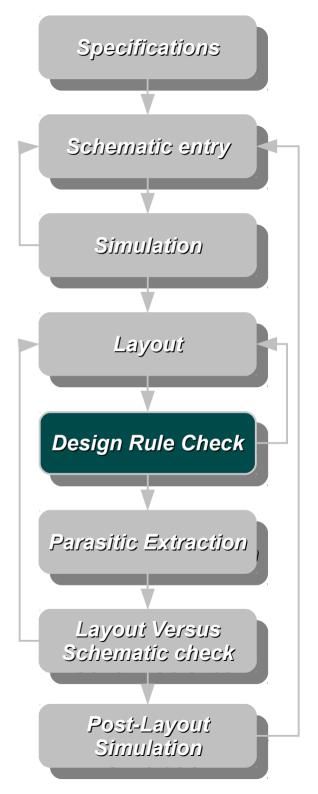






 Infinite different paths of matching what the schematic represent (art)

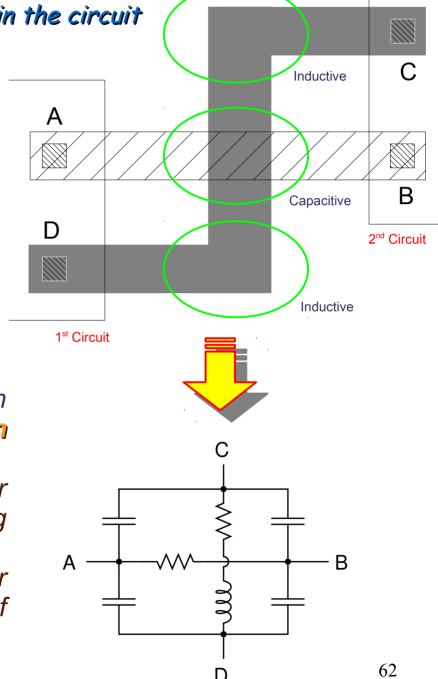




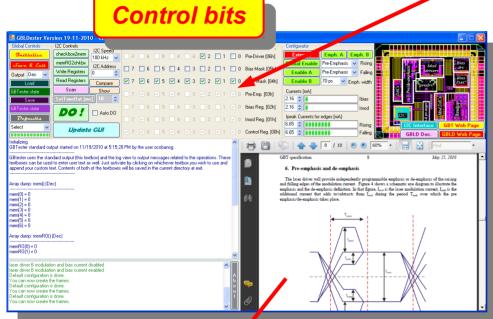
Parasitic Extraction

For a better physical representation of what is in the circuit

- Perform two simple connections:
 - → Connect the pin A to pin B with metal-1
 - → Connect the pin C to pin D with metal-2
- Designer did not draw any device but the effective circuit has at least the followings:
 - 4 capacitors
 - 2 resistors
 - → 1 inductor
- Things which are not taken into account in schematic are the parasitic devices that can not be avoided but minimized/maximized
 - → e.g. minimize input capacitance of a FE or wire capacitances between building blocks
 - → e.g. maximize narrow-band PLL filter capacitance or de-coupling capacitors of any ASIC



Test Boards and tester/configurator application



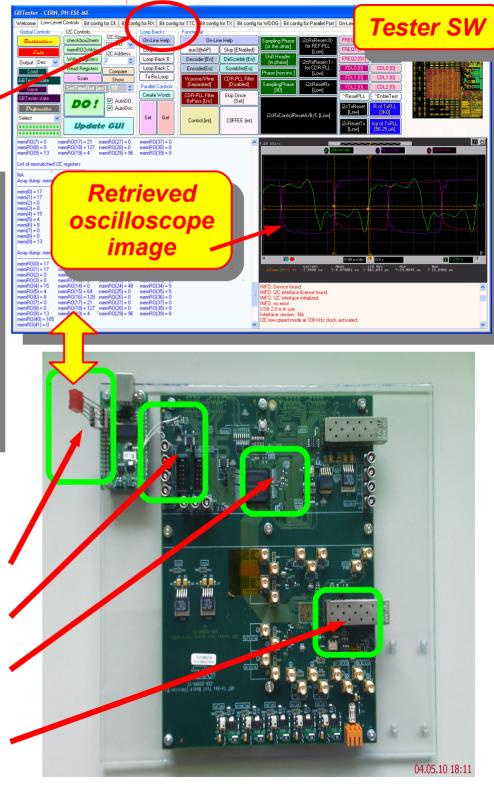
On-line documentation

 $\text{USB} \rightarrow \text{I2C adapter}$

I2C & JTAG ports

FPGA (Cyclon-III)

Where the DUT resides (DUT: Device Under Test)



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- Position-sensitive detectors | NEW
 - Resistive charge division
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- Definitions:
 - Single event upset, analog single event transient, latch-up
- Simulating radiation effects on analog circuits



Radiation Issues

Definitions and failure mechanism

- Single Event Transient (SET)
 - → A transient perturbation on an analog signal due to charge released by an ionizing radiation.
- Single Event Upset (SEU)

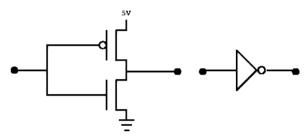
BiPolar circuit

→ State change of a digital circuit due to charge released by an ionizing radiation.

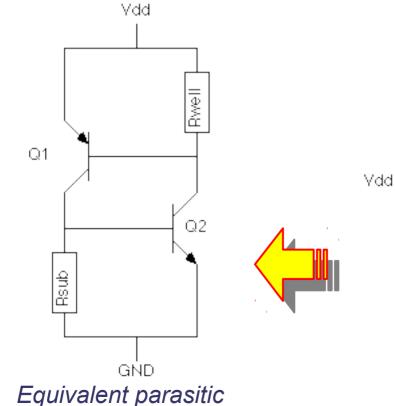
Latch-Up

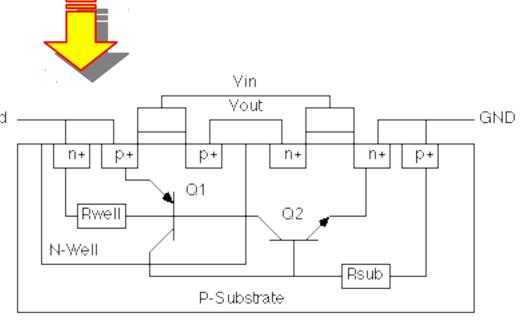
vertical PNP

→ Creation of a low-resistance path between Vdd and Gnd due to a positive feedback loop formed by parasitic devices.



CMOS inverter and its symbol

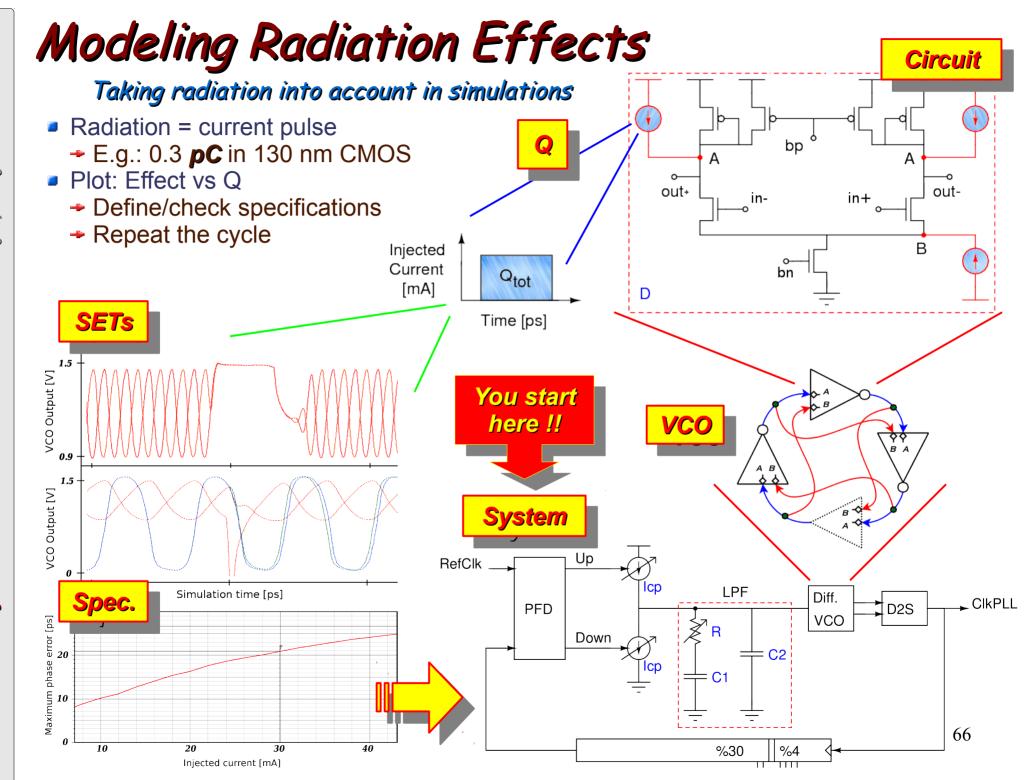




Wafer cross-section of the inverter

Jateral NPN

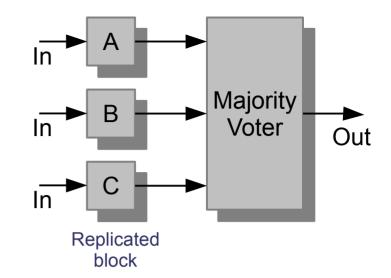
65

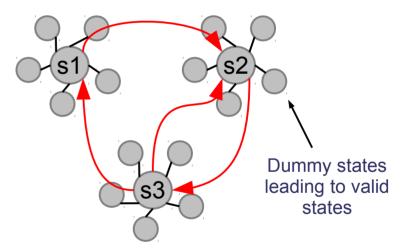


Rad-Hard Design Tricks

Adding robustness to circuits

- Use higher current levels and/or larger devices
 - → The current/voltage excursions ionizing particles generate stay insignificant
 - → Prise to pay: increased circuit footprint and power dissipation, slower operation, etc.
- Use triple-well and/or guard-ring structures frequently
 - → To ground any noise before it reaches to sensitive circuitry
- Use Modular Redundancy (nMR)
 - → Replicate circuitry and vote at the output, Triple Modular Redundancy (TMR) is commonly used
 - → The probability for an ionizing particle to affect all the three blocks at the same time is very low, therefore this technique is commonly used to harden designs against SEU





- Use dummy states to protect Finite State Machines (FSM) against SEUs
 - → If a state change occurs due to an ionizing particle passage, the FSM can return to a valid state without impairing
 - → Prise to pay: more complex FSM design, increased power dissipation and circuit footprint
- Place the ASICs within magnet **shadows** (where applicable)
 - → To decrease radiation tolerance requirements

Introduction to the Design of Full-Custom Front-End & Data Transmission ASICs*

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